

Title (en)
HOT ELECTRON TRANSISTOR

Title (de)
HEISSELEKTRONEN-TRANSISTOR

Title (fr)
TRANSISTOR A ELECTRONS CHAUDS

Publication
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Application
EP 05739776 A 20050425

Priority
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Abstract (en)
[origin: WO2005106927A2] A hot electron transistor includes an emitter electrode, a base electrode, a collector electrode, and a first tunneling structure disposed and serving as a transport of electrons between the emitter and base electrodes. The first tunneling structure includes at least a first amorphous insulating layer and a different, second insulating layer such that the transport of electrons includes transport by means of tunneling. The transistor further includes a second tunneling structure disposed between the base and collector electrodes. The second tunneling structure serves as a transport of at least a portion of the previously mentioned electrons between the base and collector electrodes by means of ballistic transport such that the portion of the electrons is collected at the collector electrode. An associated method for reducing electron reflection at interfaces in a thin-film transistor is also disclosed.

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